Preferred Device

Surface Mount Schottky Power Rectifier

... employing the Schottky Barrier principle in a large area metal-to-silicon power diode. State-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes, in surface mount applications where compact size and weight are critical to the system.

- Small Compact Surface Mountable Package with J-Bend Leads
- Rectangular Package for Automated Handling
- Highly Stable Oxide Passivated Junction
- Excellent Ability to Withstand Reverse Avalanche Energy Transients
- Guardring for Stress Protection

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 217 mg (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped in 16 mm Tape and Reel, 2500 units per reel
- Polarity: Notch in Plastic Body Indicates Cathode Lead
- ESD Ratings: Machine Model = C Human Body Model = 3B

• Marking: B310

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	100	Volts
Average Rectified Forward Current (At Rated V _R , T _L = 100°C)	I _{F(AV)}	3.0	Amps
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I _{FSM}	130	Amps
Operating Junction Temperature Range	TJ	– 65 to +150	°C

THERMAL CHARACTERISTICS

Thermal Resistance – Junction to Lead $R_{\theta JL}$	11 °C/W
-------------------------------------------------------	---------



ON Semiconductor™

http://onsemi.com

SCHOTTKY BARRIER RECTIFIERS 3.0 AMPERES 100 VOLTS



SMC CASE 403 PLASTIC

MARKING DIAGRAM



Y = Year WW = Work Week B310 = Device Code

ORDERING INFORMATION

Device	Package	Shipping	
MBRS3100T3	SMC	2500/Tape & Reel	

Preferred devices are recommended choices for future use and best overall value.

MBRS3100T3

些部TRICASSHIARACTERIATIES

Maximum Instantaneous Forward Voltage (Note 1)	V_{F}		Volts
$(i_F = 3.0 \text{ A}, T_J = 25^{\circ}\text{C})$		0.79	
$(i_F = 6.0 \text{ A}, T_J = 25^{\circ}\text{C})$		0.90	
$(i_F = 3.0 \text{ A}, T_J = 125^{\circ}\text{C})$		0.62	
$(i_F = 6.0 \text{ A}, T_J = 125^{\circ}\text{C})$		0.70	
Maximum Instantaneous Reverse Current (Note 1)	i _R		mA
(Rated dc Voltage, T _J = 25°C)		0.05	
(Rated dc Voltage, T _J = 125°C)		5.0	

^{1.} Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

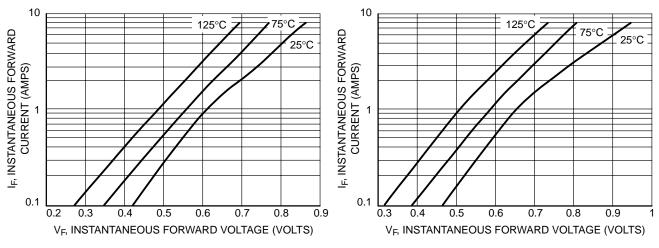


Figure 1. Typical Forward Voltage

Figure 2. Maximum Forward Voltage

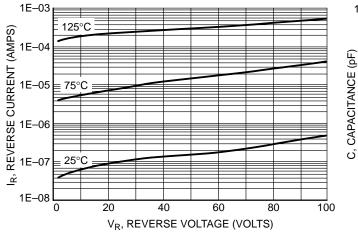


Figure 3. Typical Reverse Current

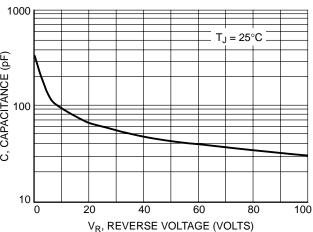


Figure 4. Typical Capacitance

MBRS3100T3

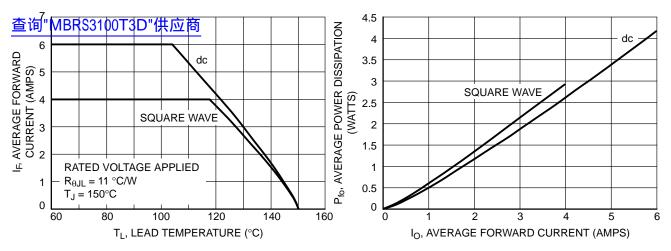


Figure 5. Current Derating - Lead

Figure 6. Forward Power Dissipation

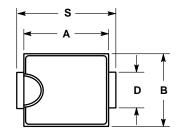
MBRS3100T3

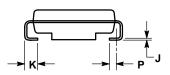
查询"MBRS3100T3D"供应商

PACKAGE DIMENSIONS

SMC

PLASTIC PACKAGE CASE 403–03 ISSUE B







NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
 Y14 5M 1982
- Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.
- 3. D DIMENSION SHALL BE MEASURED WITHIN DIMENSION P.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.260	0.280	6.60	7.11
В	0.220	0.240	5.59	6.10
С	0.075	0.095	1.90	2.41
D	0.115	0.121	2.92	3.07
Н	0.0020	0.0060	0.051	0.152
J	0.006	0.012	0.15	0.30
K	0.030	0.050	0.76	1.27
Р	0.020 REF		0.51 REF	
S	0.305	0.320	7.75	8.13

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer.

PUBLICATION ORDERING INFORMATION

Literature Fulfillment

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA

Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada **Fax**: 303–675–2176 or 800–344–3867 Toll Free USA/Canada

Email: ONlit@hibbertco.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

JAPAN: ON Semiconductor, Japan Customer Focus Center

4-32-1 Nishi-Gotanda, Shinagawa-ku, Tokyo, Japan 141-0031

Phone: 81–3–5740–2700 Email: r14525@onsemi.com

ON Semiconductor Website: http://onsemi.com

For additional information, please contact your local

Sales Representative.